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MM54HC273/MM74HC273

# MM54HC273/MM74HC273 Octal D Flip-Flops with Clear

## General Description

These edge triggered flip-flops utilize advanced silicon-gate CMOS technology to implement D-type flip-flops. They possess high noise immunity, low power, and speeds comparable to low power Schottky TTL circuits. This device contains 8 master-slave flip-flops with a common clock and common clear. Data on the D input having the specified setup and hold times is transferred to the Q output on the low to high transition of the CLOCK input. The CLEAR input when low, sets all outputs to a low state.

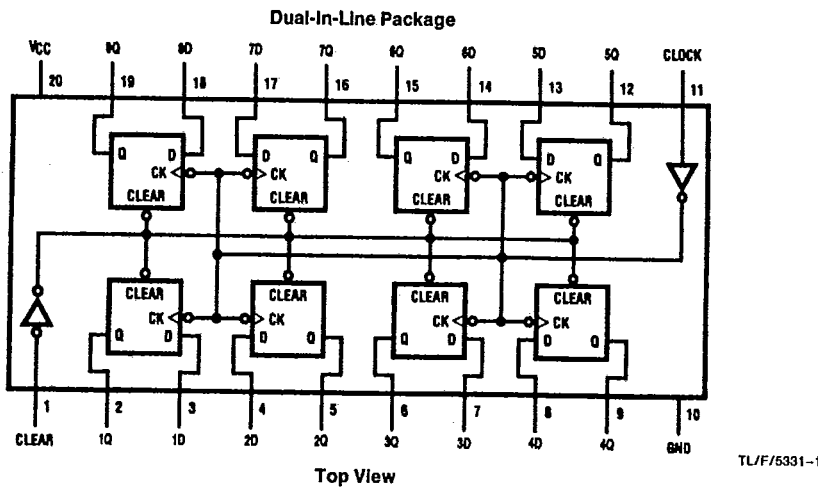
Each output can drive 10 low power Schottky TTL equivalent loads. The MM54HC273/MM74HC273 is functionally

as well as pin compatible to the 54LS273/74LS273. All inputs are protected from damage due to static discharge by diodes to  $V_{CC}$  and ground.

## Features

- Typical propagation delay: 18 ns
- Wide operating voltage range
- Low input current: 1  $\mu$ A maximum
- Low quiescent current: 80  $\mu$ A (74 Series)
- Output drive: 10 LS-TTL loads

## Connection Diagram



Order Number MM54HC273\* or MM74HC273\*

\*Please look into Section 8, Appendix D for availability of various package types.

## Truth Table

(Each Flip-Flop)

Inputs			Outputs
Clear	Clock	D	Q
L	X	X	L
H	↑	H	H
H	↑	L	L
H	L	X	$Q_0$

H = high level (steady state)  
 L = low level (steady state)  
 X = don't care  
 ↑ = transition from low to high level  
 $Q_0$  = the level of Q before the indicated steady state input conditions were established

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**Absolute Maximum Ratings** (Notes 1 and 2)

If Military/Aerospace specified devices are required, contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (V <sub>CC</sub> )	-0.5 to +7.0V
DC Input Voltage (V <sub>IN</sub> )	-1.5 to V <sub>CC</sub> +1.5V
DC Output Voltage (V <sub>OUT</sub> )	-0.5 to V <sub>CC</sub> +0.5V
Clamp Diode Current (I <sub>IK</sub> , I <sub>OK</sub> )	±20 mA
DC Output Current, per pin (I <sub>OUT</sub> )	±25 mA
DC V <sub>CC</sub> or GND Current, per pin (I <sub>CC</sub> )	±50 mA
Storage Temperature Range (T <sub>STG</sub> )	-65°C to +150°C
Power Dissipation (P <sub>D</sub> )	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temp. (T <sub>L</sub> ) (Soldering 10 seconds)	260°C

**Operating Conditions**

Supply Voltage (V <sub>CC</sub> )	Min	Max	Units
	2	6	V
DC Input or Output Voltage (V <sub>IN</sub> , V <sub>OUT</sub> )	0	V <sub>CC</sub>	V
Operating Temp. Range (T <sub>A</sub> )			
MM74HC	-40	+85	°C
MM54HC	-55	+125	°C
Input Rise or Fall Times (t <sub>r</sub> , t <sub>f</sub> )			
V <sub>CC</sub> =2.0V		1000	ns
V <sub>CC</sub> =4.5V		500	ns
V <sub>CC</sub> =6.0V		400	ns

**DC Electrical Characteristics** (Note 4)

Symbol	Parameter	Conditions	V <sub>CC</sub>	T <sub>A</sub> = 25°C			Units	
				Typ	Guaranteed Limits			
				74HC		54HC		
				T <sub>A</sub> = -40 to 85°C		T <sub>A</sub> = -55 to 125°C		
V <sub>IH</sub>	Minimum High Level Input Voltage		2.0V		1.5	1.5	V	
			4.5V		3.15	3.15	V	
			6.0V		4.2	4.2	V	
V <sub>IL</sub>	Maximum Low Level Input Voltage**		2.0V		0.5	0.5	V	
			4.5V		1.35	1.35	V	
			6.0V		1.8	1.8	V	
V <sub>OH</sub>	Minimum High Level Output Voltage	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>  I <sub>OUT</sub>   ≤ 20 μA	2.0V	2.0	1.9	1.9	V	
			4.5V	4.5	4.4	4.4	V	
			6.0V	6.0	5.9	5.9	V	
		V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>  I <sub>OUT</sub>   ≤ 4.0 mA  I <sub>OUT</sub>   ≤ 5.2 mA	4.5V	4.2	3.98	3.84	3.7	V
			6.0V	5.7	5.48	5.34	5.2	V
V <sub>OL</sub>	Maximum Low Level Output Voltage	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>  I <sub>OUT</sub>   ≤ 20 μA	2.0V	0	0.1	0.1	V	
			4.5V	0	0.1	0.1	V	
			6.0V	0	0.1	0.1	V	
		V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>  I <sub>OUT</sub>   ≤ 4 mA  I <sub>OUT</sub>   ≤ 5.2 mA	4.5V	0.2	0.26	0.33	0.4	V
			6.0V	0.2	0.26	0.33	0.4	V
I <sub>IN</sub>	Maximum Input Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	6.0V		±0.1	±1.0	μA	
I <sub>CC</sub>	Maximum Quiescent Supply Current	V <sub>IN</sub> = V <sub>CC</sub> or GND I <sub>OUT</sub> = 0 μA	6.0V		8	80	160	μA

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.  
 Note 2: Unless otherwise specified all voltages are referenced to ground.  
 Note 3: Power Dissipation temperature derating — plastic "N" package: -12 mW/°C from 65°C to 85°C; ceramic "J" package: -12 mW/°C from 100°C to 125°C.  
 Note 4: For a power supply of 5V ±10% the worst case output voltages (V<sub>OH</sub> and V<sub>OL</sub>) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V<sub>IH</sub> and V<sub>IL</sub> occur at V<sub>CC</sub>=5.5V and 4.5V respectively. (The V<sub>IH</sub> value at 5.5V is 3.85V.) The worst case leakage current (I<sub>IN</sub>, I<sub>CC</sub>, and I<sub>OZ</sub>) occur for CMOS at the higher voltage and so the 6.0V values should be used.  
 \*\*V<sub>IL</sub> limits are currently tested at 20% of V<sub>CC</sub>. The above V<sub>IL</sub> specification (30% of V<sub>CC</sub>) will be implemented no later than Q1, CY'89.

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**AC Electrical Characteristics**  $V_{CC}=5V, T_A=25^{\circ}C, C_L=15\text{ pF}, t_r=t_f=6\text{ ns}$

Symbol	Parameter	Conditions	Typ	Guaranteed Limit	Units
f <sub>MAX</sub>	Maximum Operating Frequency		50	30	MHz
t <sub>PHL</sub> , t <sub>PLH</sub>	Maximum Propagation Delay, Clock to Output		18	27	ns
t <sub>PHL</sub>	Maximum Propagation Delay, Clear to Output		18	27	ns
t <sub>REM</sub>	Minimum Removal Time, Clear to Clock		10	20	ns
t <sub>s</sub>	Minimum Setup Time Data to Clock		10	20	ns
t <sub>H</sub>	Minimum Hold Time Clock to Data		-2	0	ns
t <sub>w</sub>	Minimum Pulse Width Clock or Clear		10	16	ns

**AC Electrical Characteristics**  $C_L=50\text{ pF}, t_r=t_f=6\text{ ns}$  (unless otherwise specified)

Symbol	Parameter	Conditions	V <sub>CC</sub>	T <sub>A</sub> = 25°C		74HC	54HC	Units
				Typ	Guaranteed Limits		T <sub>A</sub> = -40 to 85°C	
f <sub>MAX</sub>	Maximum Operating Frequency		2.0V	16	5	4	3	MHz
			4.5V	74	27	21	18	MHz
			6.0V	78	31	24	20	MHz
t <sub>PHL</sub> , t <sub>PLH</sub>	Maximum Propagation Delay, Clock to Output		2.0V	38	135	170	205	ns
			4.5V	14	27	34	41	ns
			6.0V	12	23	29	35	ns
t <sub>PHL</sub>	Maximum Propagation Delay, Clear to Output		2.0V	42	135	170	205	ns
			4.5V	19	27	34	41	ns
			6.0V	18	23	29	35	ns
t <sub>REM</sub>	Minimum Removal Time Clear to Clock		2.0V	0	25	32	37	ns
			4.5V	0	5	6	7	ns
			6.0V	0	4	5	6	ns
t <sub>s</sub>	Minimum Setup Time Data to Clock		2.0V	28	100	125	150	ns
			4.5V	7	20	25	30	ns
			6.0V	5	17	21	25	ns
t <sub>H</sub>	Minimum Hold Time Clock to Data		2.0V	-15	0	0	0	ns
			4.5V	-6	0	0	0	ns
			6.0V	-4	0	0	0	ns
t <sub>w</sub>	Minimum Pulse Width Clock or Clear		2.0V	34	80	100	120	ns
			4.5V	11	16	20	24	ns
			6.0V	10	14	18	20	ns
t <sub>r</sub> , t <sub>f</sub>	Maximum Input Rise and Fall Time, Clock		2.0V		1000	1000	1000	ns
			4.5V		500	500	500	ns
			6.0V		400	400	400	ns
t <sub>THL</sub> , t <sub>TLH</sub>	Maximum Output Rise and Fall Time		2.0V	28	75	95	110	ns
			4.5V	11	15	19	22	ns
			6.0V	9	13	16	19	ns
C <sub>PD</sub>	Power Dissipation Capacitance (Note 5)	(per flip-flop)		45				pF
C <sub>IN</sub>	Maximum Input Capacitance			7	10	10	10	pF

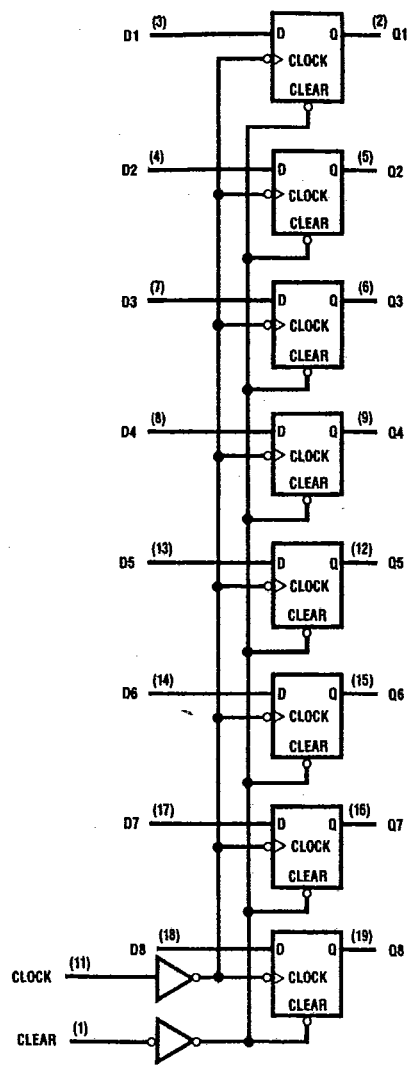
Note 5: C<sub>PD</sub> determines the no load dynamic power consumption,  $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$ , and the no load dynamic current consumption,  $I_S = C_{PD} V_{CC} f + I_{CC}$ .

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Logic Diagram

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TL/F/5331-2